TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7WHU04FU, TC7WHU04FK

TRIPLE INVERTER

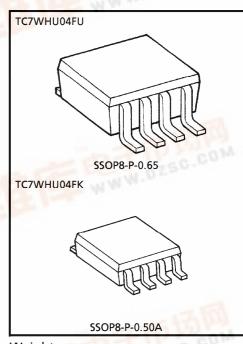
The TC7WHU04 is an advanced high speed CMOS INVERTER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. Since the internal circuit is composed of a single stage inverter, it can be used in analog applications such as crystal oscillators. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

•	High Speed	$t_{pd} = 3.5$ ns (Typ.) at
•	Low Power Dissipation	$V_{CC} = 5V$ $I_{CC} = 2\mu A \text{ (Max.) at}$

High Noise Immunity VNIH = VNIL = 10% VCC

- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ····· t_{pLH}≒t_{pHL}
- Wide Operating Voltage Range ··· \dot{V}_{CC} (opr) = 2~5.5V

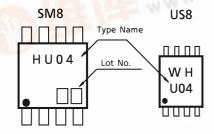


Weight

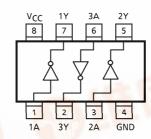
SSOP8-P-0.65 : 0.02g (Typ.) SSOP8-P-0.50A : 0.01g (Typ.)

MARKING

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PIN ASSIGNMENT (TOP VIEW)



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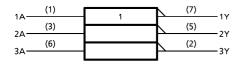
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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage Range	Vcc	-0.5~7.0	V	
DC Input Voltage	VIN	-0.5~7.0	V	
DC Output Voltage	Vout	-0.5~V _{CC} +0.5	٧	
Input Diode Current	ΙΚ	– 20	mΑ	
Output Diode Current	^I ОК	± 20	mA	
DC Output Current	lout	± 25	mA	
DC V _{CC} /Ground Current	lcc	± 50	mA	
Dawar Dissination	D-	300 (SM8)	>4/	
Power Dissipation	PD	200 (US8)	mW	
Storage Temperature	T _{stg}	-65∼150	°C	
Lead Temperature (10 s)	TL	260	°C	

LOGIC DIAGRAM



TRUTH TABLE

А	Υ
L	Н
Ι	L

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	2.0~5.5	V
Input Voltage	VIN	0~5.5	\
Output Voltage	Vout	0~V _{CC}	V
Operating Temperature	T _{opr}	- 40∼8 5	Ĵ
Input Rise And Fall Time	dt/dv	$0\sim100 \text{ (V}_{CC} = 3.3 \pm 0.3 \text{V)}$	ns/V
input Rise And Fair Time	ut/uv	$0\sim20 \ (V_{CC}=5\pm0.5V)$	115 / V

DC ELECTRICAL CHARACTERISTICS

CHADACTERISTIC	SYMBOL TEST		ONDITION	VCC	7	Ta = 25°C Ta = −40~				UNIT	
CHARACTERISTIC	STIVIBUL	TEST CONDITION		(S)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT	
High-Level				2.0	1.7	_	_	1.7			
Input Voltage	V _{IH} —		_	3.0~ 5.5	VCC VCC		_	V _C C × 0.8		V	
Low-Level				2.0	_		0.30	_	0.30		
Input Voltage	V _{IL}		$- V_{IL} = V_{IL} \qquad V_{IOH} = -50 \mu A$ $V_{IOH} = -4 \mu A$ $V_{IOH} = -8 \mu A$ $V_{IOH} = -8 \mu A$ $V_{IOL} = 50 \mu A$ $V_{IOL} = 4 \mu A$ $V_{IOL} = 8 \mu A$	3.0~ 5.5			V _C C × 0.2	_	V _{CC} ×0.2	V	
				2.0	1.8	2.0	_	1.8	_	V	
High Loyal	V _{ОН}	V _{IN} = V _{IL}	$I_{OH} = -50\mu A$	3.0	2.7	3.0	_	2.7	_		
High-Level Output Voltage				4.5	4.0	4.5	_	4.0	_		
Output Voltage		V _{IN} = GND	$I_{OH} = -4mA$	3.0	2.58	_	_	2.48			
			$I_{OH} = -8mA$	4.5	3.94	1	_	3.80	1		
		V _{IN} = V _{IH}	I _{OL} = 50μA	2.0	_	0.0	0.2	_	0.2	V	
Low-Level				3.0	_	0.0	0.3	_	0.3		
Output Voltage	VOL			4.5	_	0.0	0.5	_	0.5		
Toutput Voltage		$V_{IN} = V_{CC}$	$I_{OL} = 4mA$	3.0	_	_	0.36	_	0.44	.	
			$I_{OL} = 8mA$	4.5	_		0.36	_	0.44		
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND		0~ 5.5			± 0.1	_	± 1.0	μ A	
Quiescent Supply Current	lcc	V _{IN} = V _{CC} or GND		5.5	_	_	2.0	_	20.0	μΑ	

AC EI	LECTRICAL	CHARACTERISTICS	$(Input t_r = t_f = 3ns)$
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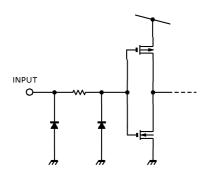
CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT	
CHARACTERISTIC	STIVIBOL		V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
	^t pLH ^t pHL	_	3.3 ± 0.3	15		5.0	8.9	1.0	10.5	ns
Propagation Delay				50		7.5	11.4	1.0	13.0	
Time			5.0 ± 0.5	15		3.5	5.5	1.0	6.5	
				50		5.0	7.0	1.0	8.0	
Input Capacitance	C _{IN}		_			5	10	_	10	рF
Power Dissipation	CDD	(Note 1)	1)			11				рF
Capacitance	itance CPD (Note 1)									ρı

(Note 1): C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC}(opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

NOISE CHARACTERISTICS (Ta = 25°C, Input $t_r = t_f = 3ns$)

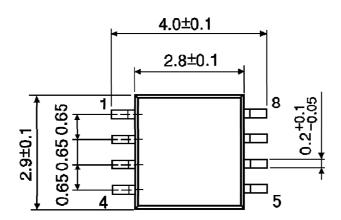
CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF	5.0	0.3	0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF	5.0	-0.3	-0.8	V
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF	5.0	_	4.0	٧
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	_	1.0	٧

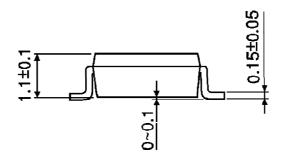
INPUT EQUIVALENT CIRCUIT



OUTLINE DRAWING SSOP8-P-0.65

Unit: mm

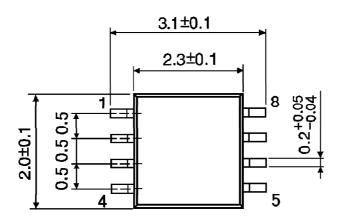


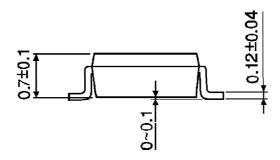


Weight: 0.02g (Typ.)

OUTLINE DRAWING SSOP8-P-0.50A

Unit: mm





Weight: 0.01g (Typ.)